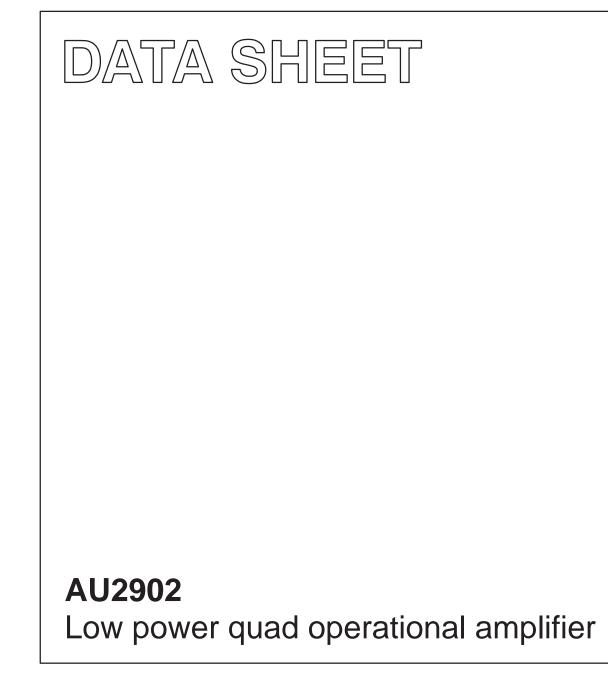
INTEGRATED CIRCUITS



Product data Supersedes data of 1994 Aug 31 File under Integrated Circuits, IC11 Handbook 2001 Aug 03



AU2902

DESCRIPTION

The AU2902 consists of four independent, high-gain, internally frequency-compensated operational amplifiers designed specifically to operate from a single power supply over a wide range of voltages.

UNIQUE FEATURES

In the linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

The unity gain crossover frequency and the input bias current are temperature-compensated.

FEATURES

- Internally frequency-compensated for unity gain
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1 MHz (temperature-compensated)
- Wide power supply range Single supply: 3 V_{DC} to 30 V_{DC} or dual supplies: ± 1.5 V_{DC} to ± 15 V_{DC}
- Very low supply current drain: essentially independent of supply voltage (1 mW/op amp at +5 V_{DC})
- Low input bias current: 45 nA_{DC} (temperature-compensated)
- Low input offset voltage: 2 mV_{DC} and offset current: 5nA_{DC}
- Differential input voltage range equal to the power supply voltage
- Large output voltage: 0 V_{DC} to V_{CC} 1.5 V_{DC} swing

EQUIVALENT SCHEMATIC

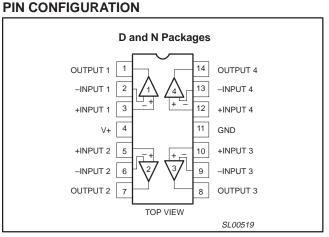


Figure 1. Pin Configuration

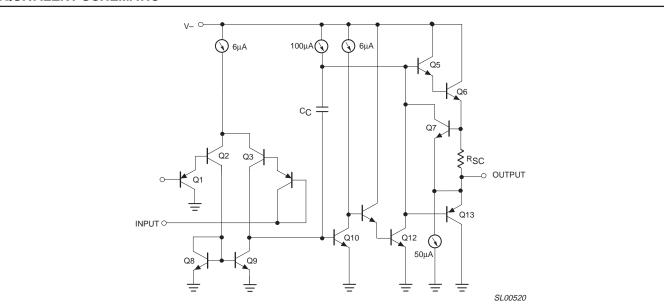


Figure 2. Equivalent Schematic

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Small Outline (SO) Package	–40 °C to +125 °C	AU2902D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	–40 °C to +125 °C	AU2902N	SOT27-1

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	32 or ±16	V _{DC}
V _{IN}	Differential input voltage	32	V _{DC}
V _{IN}	Input voltage	-0.3 to +32	V _{DC}
P _{DMAX}	Maximum power dissipation; T _{amb} = 25 °C (still-air) ¹ N package D package	1420 1040	mW mW
	Output short-circuit to GND; one amplifier V_{CC} < 15 V_{DC} and T_{amb} = 25 °C	Continuous	
I _{IN}	Input current (V _{IN} < -0.3 V) ³	50	mA
T _{amb}	Operating ambient temperature range	-40 to +125	°C
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

1. Derate above 25 °C at the following rates:

N package at 11.4 mW/°C

D package at 8.3 mW/°C

Short-circuits from the output to V_{CC}+ can cause excessive heating and eventual destruction. The maximum output current is approximately 40 mA, independent of the magnitude of V_{CC}. At values of supply voltage in excess of +15 V_{DC} continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.
This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the

3. This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input bias clamps. In addition, there is also lateral NPN parasitic transistor action on the IC chip. This action can cause the output voltages of the op amps to go to the V+ rail (or to ground for a large overdrive) during the time that the input is driven negative.

AU2902

Low power quad operational amplifier

DC ELECTRICAL CHARACTERISTICS

 $V_{CC} = 5 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}; \text{ unless otherwise specified.}$

CVMDO	DADAMETED	TEAT CONDITIONS					
SYMBOL	PARAMETER	TEST CONDITIONS	Min Typ		Max	UNIT	
	Offensional lange 1	R _S = 0 Ω		±2	±3	mV	
Vos	Offset voltage ¹	$R_{S} = 0 \Omega$, over temp.		1	±5	mV	
ΔV _{OS} /ΔT	Temperature drift	$R_{S} = 0 \Omega$, over temp.		7		μV/°C	
	lanut ourroat ²	I _{IN} (+) or I _{IN} (–)		45	250	nA	
BIAS	Input current ²	I _{IN} (+) or I _{IN} (–); over temp.		40	500	nA	
ΔΙ _{ΒΙΑS} /ΔΤ	Temperature drift	Over temp.		50		pA/∘C	
	Offset current	I _{IN} (+)–I _{IN} (–)		±5	±50	nA	
os	Oliset current	$I_{IN}(+) - I_{IN}(-)$; over temp.			±150	nA	
ΔI _{OS} /ΔT	Temperature drift	Over temp.		10		pA/°C	
	Common-mode voltage range ³	$V_{CC} \le 30 V$	0		V _{CC} – 1.5	V	
V _{CM}		$V_{CC} \le 30$ V; over temp.	0		$V_{CC} - 2$	V	
CMRR	Common-mode rejection ratio	$V_{CC} = 30 V$	65	70		dB	
V _{OUT}	Output voltage swing	$R_L = 2 \text{ k}\Omega; V_{CC} = 30 \text{ V}; \text{ over temp.}$	26			V	
V _{OH}	Output voltage high	$R_L \geq$ 10 kΩ; V_{CC} = 30 V; over temp.	27	28		V	
V _{OL}	Output voltage low	$R_L \leq$ 10 kΩ; V_{CC} = 5 V; over temp.		5	20	mV	
Icc	Supply current	$R_L = \infty$; $V_{CC} = 30$ V; over temp.		1.5	3	mA	
		$R_L = \infty$; $V_{CC} = 5$ V; over temp.		0.7	1.2	mA	
	Large-signal voltage gain	V_{CC} = 15 V (for large V _O swing); $R_L \ge 2 \ k\Omega$	25	100		V/mV	
A _{VOL}		V_{CC} = 15V (for large V _O swing); R _L ≥ 2 kΩ; over temp.	15			V/mV	
	Amplifier-to-amplifier coupling ⁵	f = 1 kHz to 20 kHz; input referred		-120		dB	
PSRR	Power supply rejection ratio	R _S = 0 Ω	65	100		dB	
	Outrast outrast	V _{IN} + = +1 V; V _{IN} - = 0 V; V _{CC} = 15 V	20	40		mA	
	Output current, Source	V_{IN} + = +1 V; V_{IN} - = 0 V; V_{CC} = 15 V; over temp.	10	20		mA	
оит	Output current, Sink	V _{IN} -=+1 V, V _{IN} +=0 V; V+=15 V	10	20		mA	
		V_{IN} = +1 V; V_{IN} + = 0 V; V_{CC} = 15 V; over temp.	5	8		mA	
		V _{IN} -= +1 V; V _{IN} + = 0 V; V _O = 200 mV	12	50		μA	
SC	Short-circuit current ⁴		10	40	60	mA	
VDIFF	Differential input voltage ³				V _{CC}	V	
GBW	Unity gain bandwidth			1		MHz	
SR	Slew rate			0.3		V/µs	
V _{NOISE}	Input noise voltage	f = 1 kHz		40		nV/√Hz	

NOTES:

1. $V_O \approx 1.4 V_{DC}$, $R_S = 0 \Omega$ with V_{CC} from 5 V to 30 V and over full input common-mode range (0 V_{DC} + to V_{CC} –1.5 V). 2. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of 3. the common-mode voltage range is V_{CC} –1.5, but either or both inputs can go to +32 V without damage. 4. Short-circuits from the output to V_{CC} can cause excessive heating and eventual destruction. The maximum output current is approximately

40 mA independent of the magnitude of V_{CC}. At values of supply voltage in excess of +15 V_{DC}, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This 5. typically can be detected as this type of coupling increases at higher frequencies.

TYPICAL PERFORMANCE CHARACTERISTICS

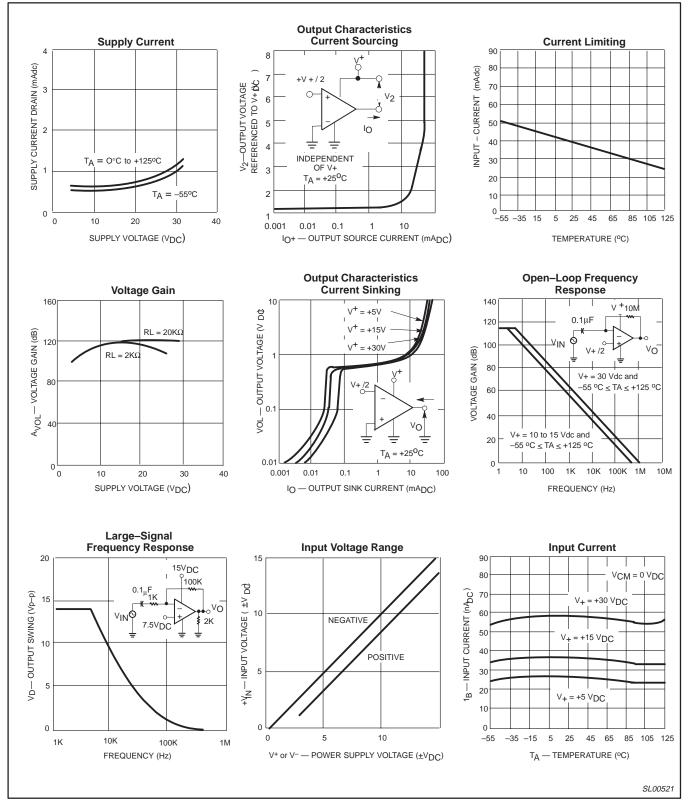


Figure 3. Typical Performance Characteristics

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Low power quad operational amplifier

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

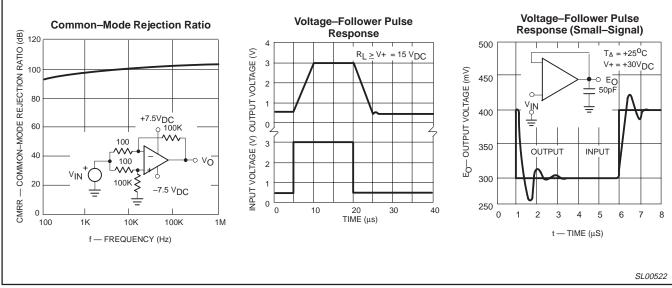


Figure 4. Typical Performance Characteristics (cont.)

TYPICAL APPLICATIONS

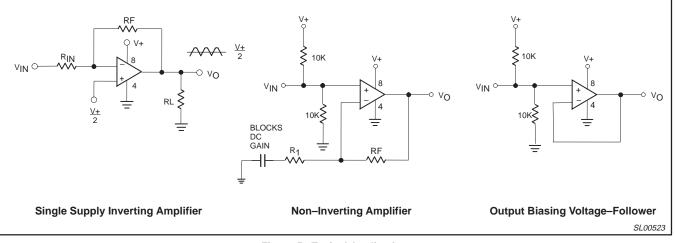
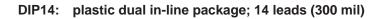
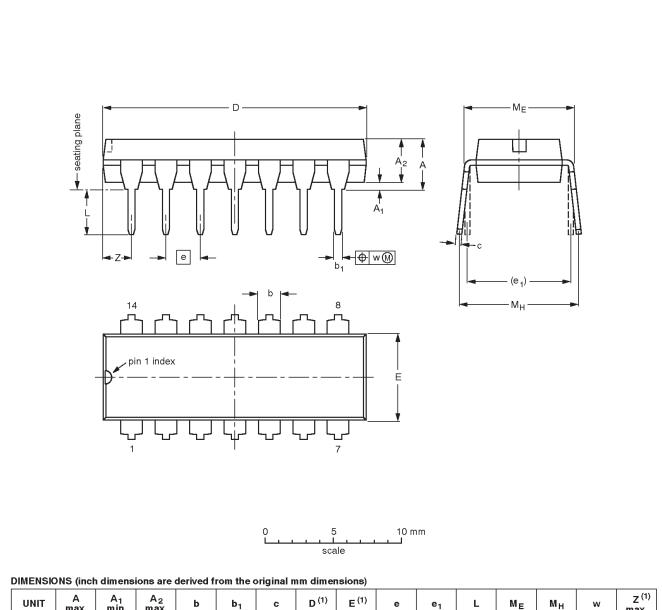


Figure 5. Typical Applications





UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	с	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	М _Н	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001	SC-501-14		-95-03-11 99-12-27

AU2902

SOT27-1

SO14: plastic small outline package; 14 leads; body width 3.9 mm SOT108-1 А X = v 🕅 A Η_E Q A2 (A_3) Α. pin 1 index H 出 出 е detail X bp 2.5 5 mm 0 scale DIMENSIONS (inch dimensions are derived from the original mm dimensions) А D⁽¹⁾ E⁽¹⁾ Z ⁽¹⁾ UNIT Q θ L v A₁ A_3 $H_{\rm E}$ Lp w У A_2 bp С е max. 0.25 1.45 0.49 0.25 8.75 4.0 6.2 1.0 0.7 0.7 mm 1.75 0.25 1.27 1.05 0.25 0.25 0.1 8.55 5.8 0.3 0.10 1.25 0.36 3.8 0.4 0.6 0.19 8⁰ 00 0.010 0.057 0.019 0.0100 0.35 0.16 0.244 0.039 0.028 0.028 0.050 0.041 0.004 inches 0.069 0.01 0.01 0.01 0.014 0.0075 0.34 0.228 0.016 0.004 0.049 0.15 0.024 0.012 Note 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

AU2902

NOTES

AU2902

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31

Fax: +31 40 27 24825

For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com

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